2SD1268

Silicon NPN epitaxial planar type

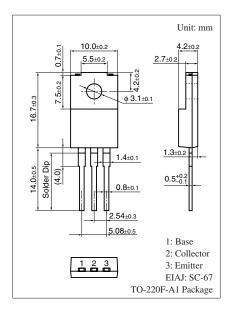
For power switching

■ Features

- ullet Low collector-emitter saturation voltage $V_{\text{CE(sat)}}$
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw.

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	130	V
Collector-emitter voltage (Base open)	V _{CEO}	80	V
Emitter-base voltage (Collector open)	V_{EBO}	7	V
Collector current	I_C	3	A
Peak collector current	I_{CP}	6	A
Collector power	P _C	30	W
dissipation $T_a = 25$ °C		2.0	
Junction temperature	T_{j}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



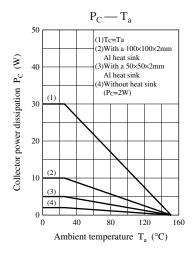
■ Electrical Characteristics $T_C = 25$ °C ± 3 °C

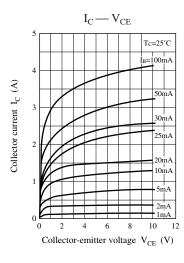
Parameter	Symbol	Conditions		Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 10 \text{ mA}, I_B = 0$	80			V
Collector-base cut-off current (Emitter open)	I_{CBO}	$V_{CB} = 100 \text{ V}, I_E = 0$			10	μΑ
Emitter-base cut-off current (Collector open)	I_{EBO}	$V_{EB} = 5 \text{ V}, I_C = 0$			50	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$	45			_
	h _{FE2} *	$V_{CE} = 2 \text{ V}, I_{C} = 0.5 \text{ A}$	60		260	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 2 A, I_B = 0.1 A$			0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 2 A, I_B = 0.1 A$			1.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = 0.5 \text{ A}, I_{B1} = 50 \text{ mA}, I_{B2} = -50 \text{ mA}$		0.5		μs
Storage time	t _{stg}	$V_{CC} = 50 \text{ V}$		2.5		μs
Fall time	t _f			0.15		μs

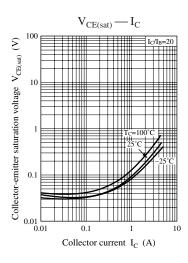
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

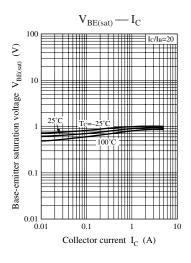
2. *: Rank classification

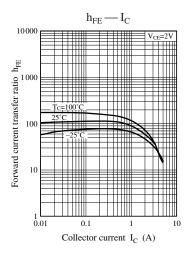
Rank	R	Q	Р
h _{FE2}	60 to 120	90 to 180	130 to 260

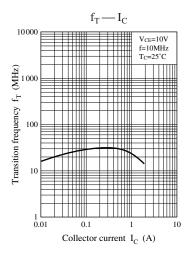


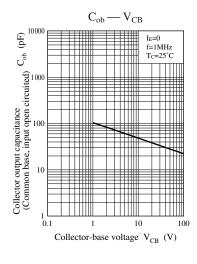


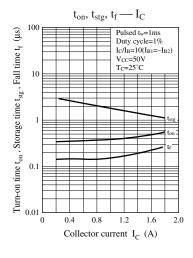


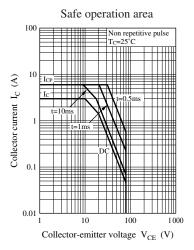












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